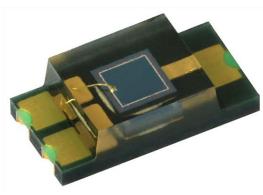


# Silicon PIN Photodiode



**DESCRIPTION** 

VEMD6010X01 is a high speed and high sensitive PIN photodiode. It is a small surface mount device (SMD) including the chip with a 0.85 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

#### **FEATURES**

Package type: surface mount

• Package form: 1206

• Dimensions (L x W x H in mm): 4 x 2 x 1.05

• Radiant sensitive area (in mm<sup>2</sup>): 0.85

· High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

• Fast response times

• Angle of half sensitivity:  $\phi = \pm 60^{\circ}$ 

• Floor life: 72 h, MSL 4, acc. J-STD-020

· Lead (Pb)-free reflow soldering

• AEC-Q101 qualified

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>



(5-2008)

AUTOMOTIVE

### **APPLICATIONS**

· High speed photo detector

| PRODUCT SUMMARY |                      |         |                       |
|-----------------|----------------------|---------|-----------------------|
| COMPONENT       | I <sub>ra</sub> (μΑ) | φ (deg) | λ <sub>0.1</sub> (nm) |
| VEMD6010X01     | 9.5                  | ± 60    | 430 to 1100           |

#### Note

• Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION |               |                              |              |  |
|----------------------|---------------|------------------------------|--------------|--|
| ORDERING CODE        | PACKAGING     | REMARKS                      | PACKAGE FORM |  |
| VEMD6010X01          | Tape and reel | MOQ: 3000 pcs, 3000 pcs/reel | 1206         |  |

### Note

MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                   |                   |             |      |  |
|--|-----------------------------------|-------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION                    | SYMBOL            | VALUE       | UNIT |  |
| Reverse voltage  |                                   | V <sub>R</sub>    | 32          | V    |  |
| Power dissipation  | T <sub>amb</sub> ≤ 25 °C          | P <sub>V</sub>    | 215         | mW   |  |
| Junction temperature   |                                   | T <sub>j</sub>    | 110         | °C   |  |
| Operating temperature range  |                                   | T <sub>amb</sub>  | -40 to +110 | °C   |  |
| Storage temperature range  |                                   | T <sub>stg</sub>  | -40 to +110 | °C   |  |
| Soldering temperature  | Acc. reflow solder profile fig. 8 | T <sub>sd</sub>   | 260         | °C   |  |
| Thermal resistance junction/ambient  | Acc. J-STD-051                    | R <sub>thJA</sub> | 270         | K/W  |  |

| PARAMETER                                 | TEST CONDITION   | SYMBOL            | MIN. | TYP.        | MAX. | UNIT |
|---|--|-------------------|------|-------------|------|------|
| Forward voltage                           | I <sub>F</sub> = 50 mA   | V <sub>F</sub>    |      | 1           |      | V    |
| Breakdown voltage                         | I <sub>R</sub> = 100 μA, E = 0   | V <sub>(BR)</sub> | 32   |             |      | V    |
| Reverse dark current                      | V <sub>R</sub> = 10 V, E = 0   | I <sub>ro</sub>   |      | 1           | 3    | nA   |
| Diode capacitance                         | V <sub>R</sub> = 0 V, f = 1 MHz, E = 0                                       | C <sub>D</sub>    |      | 12          |      | pF   |
|   | $V_R = 5 V, f = 1 MHz, E = 0$  | C <sub>D</sub>    |      | 3.6         |      | pF   |
| Open circuit voltage                      | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$                      | Vo                |      | 356         |      | mV   |
| Temperature coefficient of Vo             | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$                          | TK <sub>Vo</sub>  |      | -3.1        |      | mV/K |
| Short circuit current                     | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$                      | I <sub>k</sub>    |      | 9           |      | μA   |
| Temperature coefficient of I <sub>k</sub> | $E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$                      | TK <sub>lk</sub>  |      | 0.1         |      | %/K  |
| Reverse light current                     | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$ | I <sub>ra</sub>   | 6.7  | 9.5         | 12.4 | μA   |
| Angle of half sensitivity                 |  | φ                 |      | ± 60        |      | deg  |
| Wavelength of peak sensitivity            |  | $\lambda_{p}$     |      | 900         |      | nm   |
| Range of spectral bandwidth               |  | λ <sub>0.1</sub>  |      | 430 to 1100 |      | nm   |
| Rise time                                 | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$      | t <sub>r</sub>    |      | 100         |      | ns   |
| Fall time                                 | $V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$      | t <sub>f</sub>    |      | 100         |      | ns   |

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

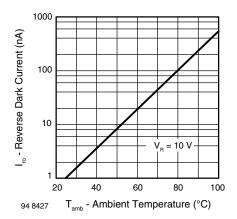


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

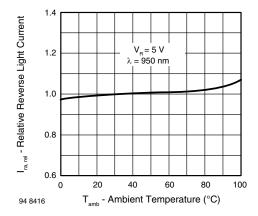


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

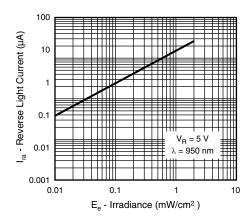


Fig. 3 - Reverse Light Current vs. Irradiance

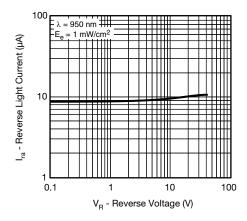


Fig. 4 - Reverse Light Current vs. Reverse Voltage

### **REFLOW SOLDER PROFILE**

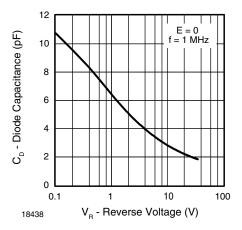


Fig. 5 - Diode Capacitance vs. Reverse Voltage

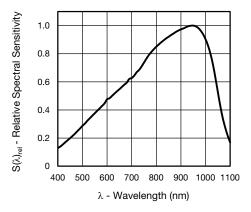


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

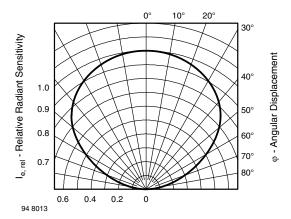


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

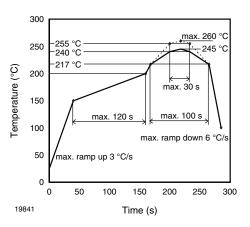


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 72 h

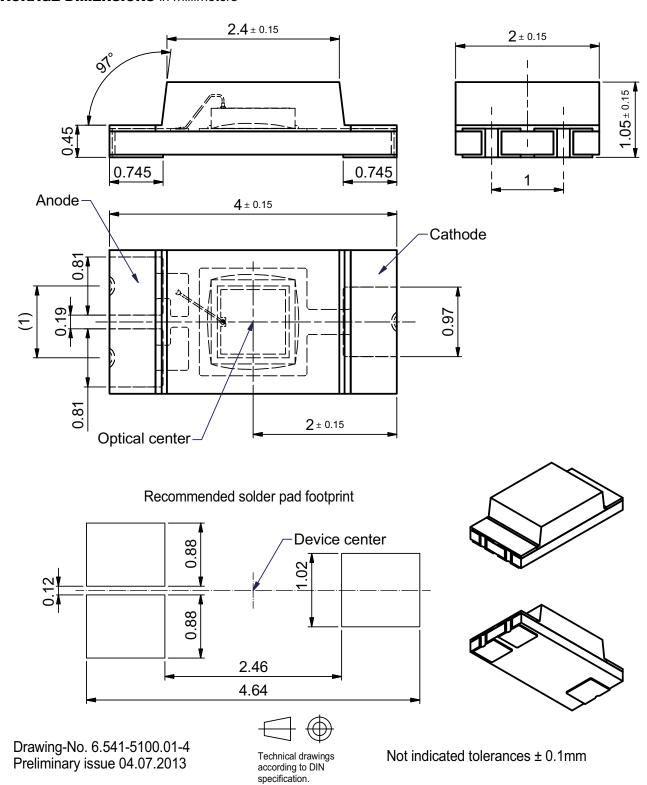
Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

Moisture sensitivity level 4, acc. to J-STD-020.

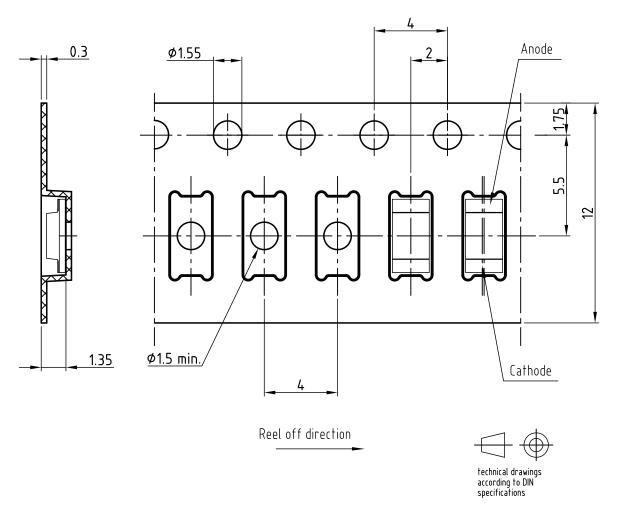
#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ K.

### **PACKAGE DIMENSIONS** in millimeters



### **BLISTER TAPE DIMENSIONS** in millimeters



Not indicated tolerances ±0.1

Drawing refers to following Types: TEMD6010FX01

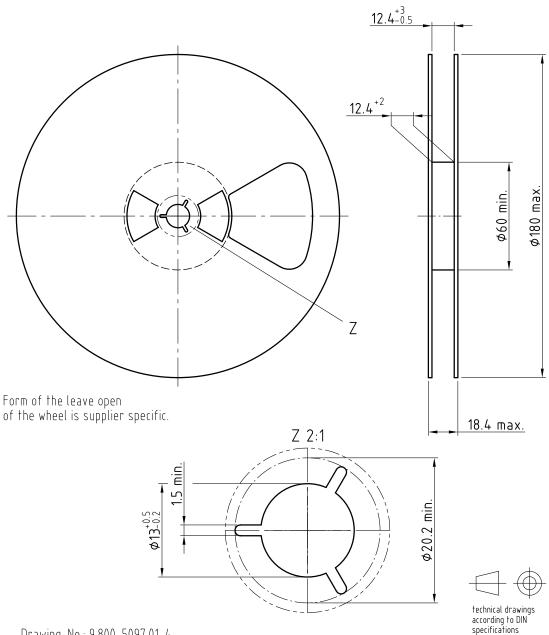
VEMD6x10X01 VEMD6x15X01

Drawing-No.: 9.700-5329.02-4

Prel Issue: 16.07.2013

All dimensions in mm

### **REEL DIMENSIONS** in millimeters



Drawing-No.: 9.800-5097.01-4

Issue: 1; 05.05.08

20874



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